

APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	STRUCTURE AND METHOD OF FORMING A BIPOLAR TRANSISTOR HAVING A SELF-ALIGNED RAISED EXTRINSIC BASE USING A LINK-UP REGION FORMED FROM AN OPENING THEREIN
Application Type :	regular, utility
Attorney Docket Number :	FIS920030410US1
Correspondence address:	
Name:	International Business Machines Corporation New Orchard Road
Address-1 of Mailing Address:	
Address-2 of Mailing Address:	
City of Mailing Address:	Armonk
State of Mailing Address:	NY
Postal Code of Mailing Address:	10504
Country of Mailing Address:	US
Phone:	
Fax:	
E-mail:	
Inventor Information:	
Inventor 1:	
Applicant Authority Type:	Inventor
Citizenship:	JO
Given Name:	Marwan
Middle Name:	H.
Family Name:	Khater
Residence:	
City of Residence:	Poughkeepsie
State of Residence:	NY
Country of Residence:	US
Address-1 of Mailing Address:	606 Hudson Harbour Drive
Address-2 of Mailing Address:	
City of Mailing Address:	Poughkeepsie
State of Mailing Address:	NY
Postal Code of Mailing Address:	12601
Country of Mailing Address:	US

Phone:

Fax:

E-mail:

Publication Information:

Suggested Figure for Publication - 1

Suggested Classification -

Suggested Technology Center -

Total Number of Drawing Sheets - 22

Assignee 1:

Organization Name: International Business Machines Corporation

Address-1 of Mailing Address: New Orchard Road

Address-2 of Mailing Address:

City of Mailing Address: Armonk

State of Mailing Address: NY

Postal Code of Mailing Address: 10504

Country of Mailing Address: US

Phone:

Fax:

E-mail: